Semiconductors

Linear I.C.'s - Audio Amplifiers

TBA810 Audio Power Amplifier with thermal shutdown

DESCRIPTION

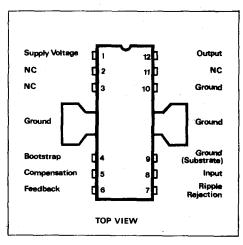
The TBA 810 S is a monolithic integrated circuit in a 12-lead quad in-line plastic package intended for use as a low frequency class B amplifier. The TBA 810 S provides 7W power output at 16V/ 4Ω , 6 W at $14.4V/4\Omega$, 2.5W at $9V/4\Omega$, 1W at $6V/4\Omega$ and works with a wide range of supply voltages (4 to 20V); it gives high output current (up to 2.5A), high efficiency (75% at 6W output,) very low harmonic and cross-over distortion. In addition. the circuit is provided with a thermal limiting circuit which fundamentally changes the criteria normally used in determining the size of the heat sink.

The TBA 810 AS has the same electrical characteristics as the TBA 810 S, but its cooling tabs are flat and pierced so that an external heat sink can easily be attached.

ABSOLUTE MAXIMUM RATINGS

Supply voltage	20V
Output peak current (non-repetitive)	3.5A
Output current (repetitive)	2.5A
Power dissipation: at T _{amb} = 70°C	1W
at Ttab = 100°C	5W
Storage and junction temperature	-40 to 150°C

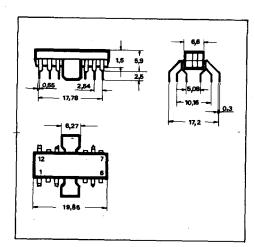
CONNECTION DIAGRAM



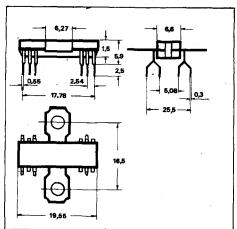
REFERENCE TABLE

Code	Stock No.	
TBA 810S TBA 810 AS	31212G 345 8 1 H	

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PHYSICAL DIMENSIONS (TBA 810 AS)

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ELECTRICAL CHARACTERISTICS ($T_{emb} \le 25^{\circ}C$)

Paramet	er	Test conditions	Min. Typ. Max.	Unit
V.	Supply voltage (pin 1)		4 20	٧
٧,	Quiescent output voltage (pin 12)		6.4 7.2 8	V
l _d	Quiescent drain current	V _a = 14.4 V	12 20	mA
l _b	Bias current (pin 8)		0.4	μΑ
P.	Power output	d = 10% R _L = 4Ω f = 1 kHz V _s = 16 V V _s = 16 V V _s = 14.4 V V _s = 9 V V _s = 6 V	7 6 2.5 1	3333
V _{I (rms)}	Input voltage		220	m٧
Vi	Input sensitivity	$P_o = 6 W$ $V_s = 14.4 V$ $R_L = 4\Omega$ $f = 1 \text{ kHz}$ $R_t = 56\Omega$ $R_t = 22\Omega$	80 35	m∨ m∨
R _i	Input resistance (pin 8)		5	MΩ
В	Frequency response (-3 dB)	$V_s = 14.4 V$ $R_L = 4\Omega$ $C3 = 820 pF$ $C3 = 1500 pF$	40 to 20,000 40 to 10,000	Hz Hz
d	distortion	$P_0 = 50 \text{ mW to 3 W}$ $V_0 = 14.4 \text{ V}$ $R_L = 4\Omega$ $f = 1 \text{ kHz}$	0.3	%
G,	Voltage gain (open loop)	V _e = 14.4 V R _L = 4Ω f = 1 kHz	80	dB
G,	Voltage gain (closed loop)	$V_a = 14.4 V$ $R_L = 4\Omega$ $f = 1 \text{kHz}$	34 37 40	dB
e _N	Input noise voltage	$V_0 = 14.4 \text{ V}$ $R_0 = 0$ $B(-3 \text{ dB}) = 20 \text{ Hz to } 20,000 \text{ Hz}$	2	μV
I _N	Input noise current	V _a = 14.4 V B(-3 dB) = 20 Hz to 20,000 Hz	0.1	nA
η	Efficiency	$P_0 = 5 W$ $V_4 = 14.4 V$ $R_L = 4\Omega$ $f = 1 \text{ kHz}$	70	%
SVR	Supply voltage rejection	$V_a = 14.4 \text{ V}$ $R_L = 4\Omega$ $f_{ripple} = 100 \text{ Hz}$	38	dB
HERMA	L DATA		TBA 810AS TB	A 810A
R _{th j-tab}	Thermal resistance junction Thermal resistance junction		12 °C/W 10 70* °C/W 80	°C/W

^{*} Obtained with tabs soldered to printed circuit with minimized copper area.